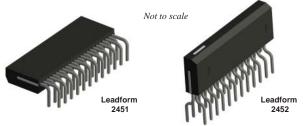


# **Features and Benefits**

- Built-in pre-drive IC
- MOSFET power element
- Alleviate noise generation by adjusting an internal resistor
- CMOS compatible input (5 V)
- High-side gate driver using bootstrap circuit or floating power supply
- Built-in protection circuit for controlling power supply voltage drop (UVLO on VCC)
- Overcurrent protection (OCP), overcurrent limiting (OCL), and thermal shutdown (TSD)
- Output of fault signal during operation of protection circuit
- Output current 2.5 A
- Small SIP (SMA 24-pin)

### Packages: Power SIP



# Description

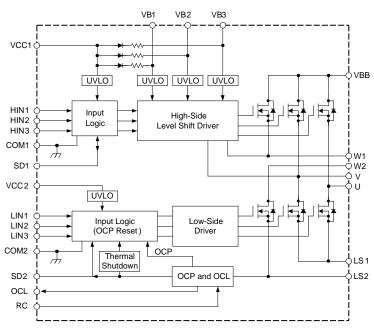
The SMA6863M inverter power module (IPM) device provides a robust, highly-integrated solution for optimally controlling 3-phase motor power inverter systems and variable speed control systems used in energy-conserving designs to drive motors of residential and commercial appliances. These ICs take 230 VAC input voltage, and 2.5 A (continuous) output current. They can withstand voltages of up to 500 V (MOSFET breakdown voltage).

The SMA6800M power package includes an IC with all of the necessary power elements (six MOSFETs), pre-driver ICs (two), and bootstrap diodes (three), needed to configure the main circuit of an inverter. This enables the main circuit of the inverter to be configured with fewer external components than traditional designs.

Applications include residential white goods (home applications) and commercial appliance motor control:

- Air conditioner fan
- Refrigerator compressor
- Dishwasher pump

# Functional Block Diagram



- A. SD1, SD2 terminals are used for both input and output.
- B. SD1, SD2, and OCL terminals are open-collector output. RC terminal is open-drain output.

C. Blanking Time ( $t_{blank}$ ) is used in Overcurrent Limiting (OCL) and Overcurrent Protection (OCP). If the time exceeds the limit, the signal will be output (open-collector output turns on), and protection operation will start up.

Figure 1. Driver block diagram.

# High Voltage 3-Phase Motor Driver

### **Selection Guide**

		MOSFET Breakdown	Output Current		
Part Number	Packing	Voltage, V <sub>DSS</sub> (min) (V)	Continuous, I <sub>O</sub> (max) (A)	Pulsed, I <sub>OP</sub> (max) (A)	
SMA6863M	18 pieces per tube	500	2.5	5	

# Absolute Maximum Ratings, valid at $T_A = 25^{\circ}C$

Characteristic	Symbol	Remarks	Rating	Unit
MOSFET Breakdown Voltage	V <sub>DSS</sub>	$V_{CC} = 15 \text{ V}, I_D = 100 \mu\text{A}, V_{IN} = 0 \text{V}$	500	V
Logic Supply Voltage	V <sub>CC</sub>	Between VCC and COM	20	V
Bootstrap Voltage	V <sub>BS</sub>	Between VB and HS (U,V, and W phases)	20	V
Output Current, Continuous	I <sub>O</sub>		2.5	A
Output Current, Pulsed	I <sub>OP</sub>	PW ≤ 100 µs, duty cycle = 1%	5	A
Input Voltage	V <sub>IN</sub>	HINx and LINx pins	-0.5 to 7	V
Pull-up Voltage for Shutdown Pins	V <sub>SDX</sub>	SDx pins	7	V
Pull-up Voltage for Overcurrent Limiting Pin	V <sub>OCL</sub>		7	V
Allowable Power Dissipation	PD	$T_{\rm C} = 25^{\circ}{\rm C}$	28	W
Thermal Resistance (Junction to Case)	R <sub>θJC</sub>	All elements operating	4.5	°C/W
Thermal Resistance (Junction to Case)	R <sub>0JA</sub>	All elements operating	31.25	°C/W
Case Operating Temperature	T <sub>COP</sub>		-20 to 100	°C
Junction Temperature (MOSFET)	TJ		150	°C
Storage Temperature	T <sub>stg</sub>		-40 to 150	°C

### **Recommended Operating Conditions**

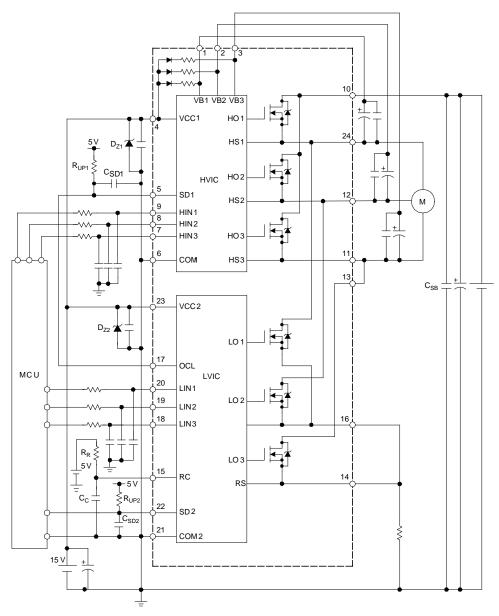
Characteristic	Symbol	Remarks	Min.	Тур.	Max.	Units
Main Supply Voltage	V <sub>BB</sub>	Between VBB and LS	-	_	400	V
V <sub>BB</sub> Snubber Capacitor	C <sub>SB</sub>		0.01	-	0.1	μF
Logic Supply Voltage	V <sub>CC</sub>	Between VCC and COM	13.5	15	16.5	V
Zener Voltage for VCCx Pins	Vz	Between VCC and COM	18	-	20	V
Pull-up Voltage	V <sub>SDx</sub> , V <sub>OCL</sub>		4.5	5	5.5	V
Pull-up Resistor SDx Pins	R <sub>UPX</sub>		3.3	-	10	kΩ
Pull-up Resistor OCL Pin	R <sub>OCL(up)</sub>		1	-	10	kΩ
Pull-up Resistor RC Pin	R <sub>R</sub>		33	-	390	kΩ
Capacitor SDX and OCL Pins	C <sub>SDX</sub> , C <sub>OCL</sub>		1	-	10	nF
Capacitor RC Pin	Cc		1	-	4.7	nF
Dead Time	t <sub>dead</sub>	$T_J = -20^{\circ}C$ to $150^{\circ}C$	1.5	-	-	μs
Misisson Israel Dates Middle	I <sub>INMIN(on)</sub>	$T_J = -20^{\circ}C$ to $150^{\circ}C$	0.5	-	-	μs
Minimum Input Pulse Width	I <sub>INMIN(off)</sub>	$T_J = -20^{\circ}C$ to $150^{\circ}C$	0.5	-	-	μs
Switching Frequency	f <sub>PWM</sub>		-	-	20	kHz
Junction Temperature	TJ		-	-	125	°C

All performance characteristics given are typical values for circuit or system baseline design only and are at the nominal operating voltage and an ambient temperature,  $T_A$ , of 25°C, unless otherwise stated.





## **Typical Application Diagram**



#### NOTE:

The external electrolytic capacitors should be placed as close to the IC as possible, in order to avoid malfunctions from external noise interference. Put a ceramic capacitor in parallel with the electrolytic capacitor if further reduction of noise susceptibility is necessary.





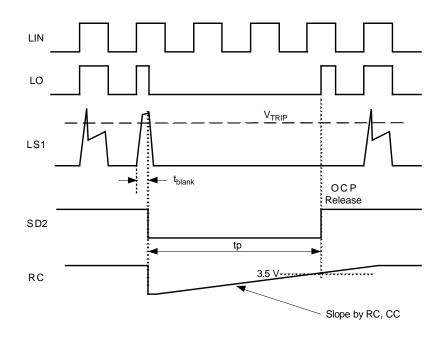
Characteristics	Symbol	Conditions	Min	Тур	Max	Units
Logic Supply Current	I <sub>CC</sub>	$V_{CC} = 15 \text{ V}, T_{C} = -20^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$	-	4.2	7	mA
Bootstrap Supply Current	I <sub>BX</sub>	$V_{BX} = 15 \text{ V}, V_{HIN} = 5 \text{ V}, T_{C} = -20^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$	-	135	380	μA
	VIH	V <sub>CC</sub> = 15 V	2.4	2.9	3.4	V
Input Voltage	VIL	V <sub>CC</sub> = 15 V	1.6	2.1	2.6	V
Input Voltage Hysteresis	V <sub>lhys</sub>	V <sub>CC</sub> = 15 V	-	0.8	_	V
Input Current	I <sub>IN</sub>	V <sub>IN</sub> = 5 V	-	230	500	μA
	V <sub>UVHL</sub>	High side, between VBx and U, V, or W	9.0	10.0	11.0	V
	V <sub>UVHH</sub>		9.5	10.5	11.5	V
	V <sub>UVHhys</sub>	High side, hysteresis	-	0.5	-	V
Undervoltage Lock Out	V <sub>UVLL</sub>	Low side, between VCC2 and COM2	10.0	11.0	12.0	V
	V <sub>UVLH</sub>		10.5	11.5	12.5	V
	V <sub>UVLhys</sub>	Low side, hysteresis	-	0.5	_	V
SDx and OCL Output Voltage	V <sub>SDX(on)</sub> , V <sub>OCL</sub>	$V_{SDX} = V_{OCL} = 5 \text{ V}, \text{ R}_{UPX} = 3.3 \text{ k}\Omega$	-	_	0.6	V
Overtemperature DetectionThreshold	T <sub>DH</sub>		120	135	150	°C
Temperature (Activation and	T <sub>DL</sub>	$V_{CC}$ = 15 V, high-side and low side	100	115	130	°C
Deactivation)	T <sub>Dhys</sub>		-	20	_	°C
Overcurrent Protection Trip Voltage	V <sub>TRIP</sub>	V <sub>CC</sub> = 15 V, T <sub>C</sub> = -20°C to 100°C	0.9	1.0	1.1	V
Overcurrent Limiting Reference Voltage	V <sub>LIM</sub>	V <sub>CC</sub> = 15 V, T <sub>C</sub> = -20°C to 100°C	0.5035	0.53	0.5565	V
Overcurrent Protection Hold Time	tp	$V_{RC} = 5 \text{ V}, \text{ R}_{R} = 360 \text{ k}\Omega, \text{ C}_{C} = 0.0047 \mu\text{F}$	-	2.0	_	ms
Blanking Time	t <sub>blank</sub>	V <sub>CC</sub> = 15 V	1.4	2.0	2.6	μs
Bootstrap Diode Leakage Current	I <sub>LBD</sub>	V <sub>R</sub> = 500 V	-	-	10	μA
Bootstrap Diode Forward Voltage	V <sub>FBD</sub>	I <sub>F</sub> = 0.15 A	-	1.1	1.3	V
Bootstrap Diode Recovery Time	t <sub>rrb</sub>	I <sub>F</sub> / I <sub>RP</sub> = 100 mA / 100 mA	-	70	_	ns
Bootstrap Diode Series Resistor	R <sub>BD</sub>		168	210	252	Ω
MOSFET Breakdown Voltage	V <sub>DSS</sub>	$V_{CC} = 15 \text{ V}, \text{ I}_{D} = 100 \mu\text{A}, V_{IN} = 0 V$	500	_	_	V
MOSFET Leakage Current	I <sub>DSS</sub>	V <sub>CC</sub> = 15 V, V <sub>DS</sub> = 500 V, V <sub>IN</sub> = 0 V	-	_	100	μA
MOSFET On State Resistance	R <sub>DS(on)</sub>	V <sub>CC</sub> = 15 V, I <sub>D</sub> = 1.5 A, V <sub>IN</sub> = 5 V	-	2.0	2.4	Ω
MOSFET Diode Forward Voltage	V <sub>SDF</sub>	V <sub>CC</sub> = 15 V, I <sub>SD</sub> = 1.5 A, V <sub>IN</sub> = 0 V	-	1.1	1.5	V
	t <sub>dH(on)</sub>		390	790	1190	ns
	t <sub>rH</sub>	$V_{BB} = 300 \text{ V}, \text{ V}_{CC} = 15 \text{ V}, \text{ I}_{D} = 2.5 \text{ A}, 0 \text{ V} \le \text{ V}_{IN} \le 5 \text{ V}$	30	60	90	ns
Switching Time, High Side	t <sub>rrH</sub>		50	115	180	ns
	t <sub>dH(off)</sub>		360	725	1090	ns
	t <sub>fH</sub>		0	20	40	ns
	t <sub>dL(on)</sub>		340	680	1020	ns
	t <sub>rL</sub>		35	70	105	ns
Switching Time, Low Side	t <sub>rrL</sub>		60	120	180	ns
	t <sub>dL(off)</sub>		300	605	910	ns
	t <sub>fL</sub>		0	20	40	ns

#### ELECTRICAL CHARACTERISTICS, valid at $T_A=25^{\circ}C$ , unless otherwise noted





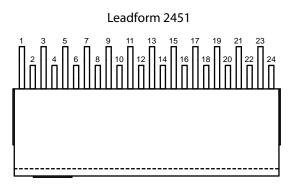
Low-Side Input/Output Timing Diagram





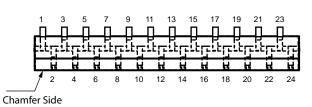


### **Pin-out Diagrams**



Chamfer on Opposite Side

# Leadform 2452



Number	Name	Function
1	VB1	High side bootstrap terminal (U phase)
2	VB2	High side bootstrap terminal (V phase)
3	VB3	High side bootstrap terminal (W phase)
4	VCC1	High side logic supply voltage
5	SD1	High side shutdown input and overtemperature fault signal output (open-collector output)
6	COM1	High side logic GND terminal
7	HIN3	High side input terminal (W phase)
8	HIN2	High side input terminal (V phase)
9	HIN1	High side input terminal (U phase)
10	VBB	Main supply voltage
11	W1	Output of W phase (connect to W2 externally)
12	V	Output of V phase
13	W2	Output of W phase (connect to W1 externally)
14	LS2	Low side emitter terminal (connect to LS1 externally)
15	RC	Overcurrent protection hold time adjustment input terminal and open-drain output
16	LS1	Low side emitter terminal (connect to LS2 externally)
17	OCL	Output for overcurrent limiting (open-collector output)
18	LIN3	Low side input terminal (W phase)
19	LIN2	Low side input terminal (V phase)
20	LIN1	Low side input terminal (U phase)
21	COM2	Low side GND terminal
22	SD2	Low side shutdown input and overtemperature and overcurrent fault signals output (open-collector output)
23	VCC2	Low side logic supply voltage
24	U	Output of U phase



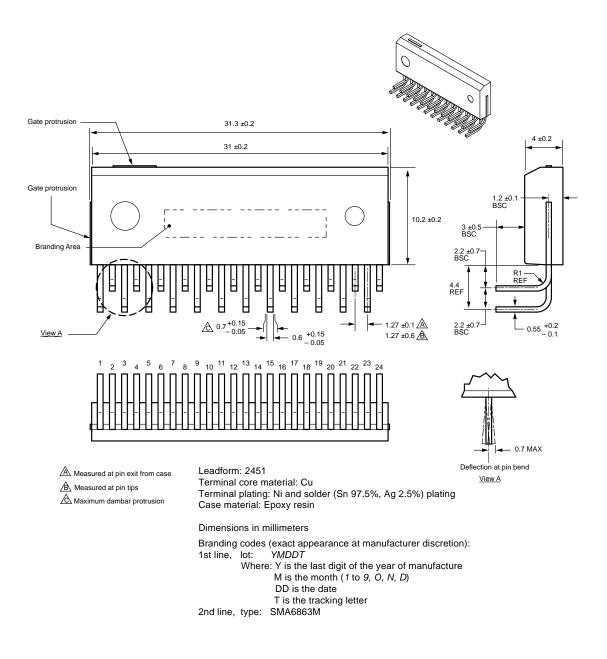


# High Voltage 3-Phase Motor Driver

# Package Outline Drawing

Leadform 2451

Dual rows, 24 alternating pins; pins bent 90° for horizontal case mounting; pin #1 in outer row





Leadframe plating Pb-free. Device composition complies with the RoHS directive.



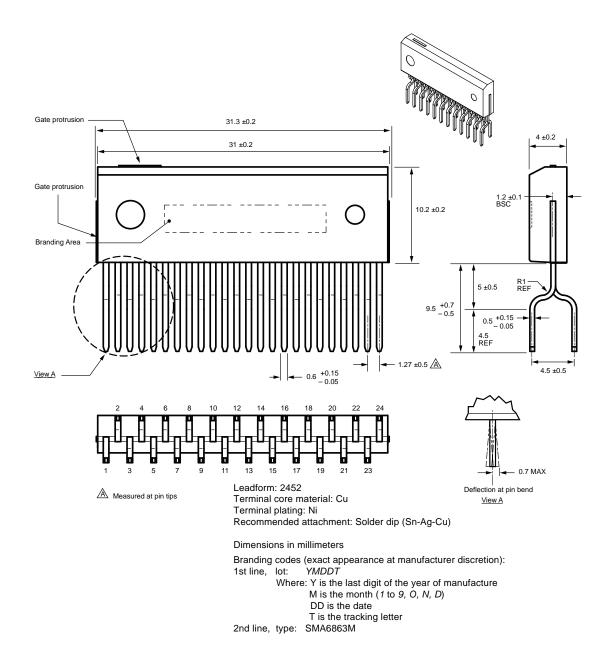


# High Voltage 3-Phase Motor Driver

# Package Outline Drawing

Leadform 2452

Dual rows, 24 alternating pins; vertical case mounting; pin #1 opposite chamfer side

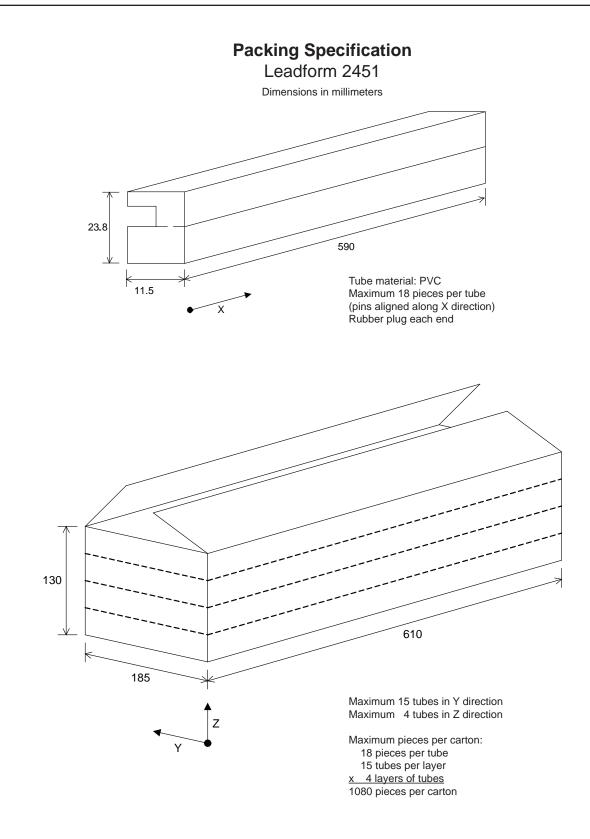


 $(\mathbb{P}_{0})$ 

Leadframe plating Pb-free. Device composition complies with the RoHS directive.

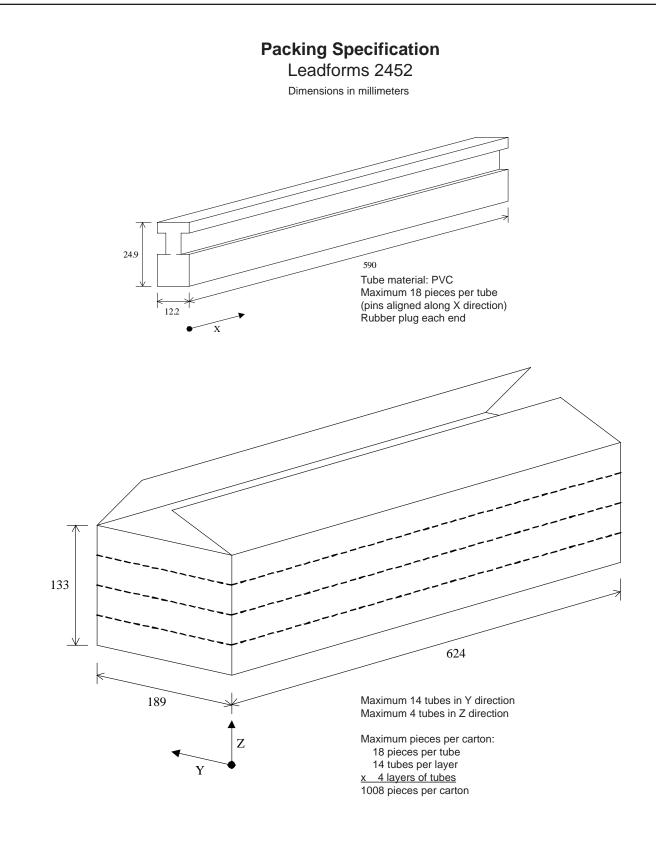
















# High Voltage 3-Phase Motor Driver



WARNING — These devices are designed to be operated at lethal voltages and energy levels. Circuit designs that embody these components must conform with applicable safety requirements. Precautions must be taken to prevent accidental contact with power-line potentials. Do not connect grounded test equipment.

The use of an isolation transformer is recommended during circuit development and breadboarding.

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

#### **Cautions for Storage**

- Ensure that storage conditions comply with the standard temperature (5°C to 35°C) and the standard relative humidity (around 40 to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of products that have been stored for a long time.

#### **Cautions for Testing and Handling**

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between adjacent products, and shorts to the heatsink.

#### Remarks About Using Silicone Grease with a Heatsink

- When silicone grease is used in mounting this product on a heatsink, it shall be applied evenly and thinly. If more silicone grease than required is applied, it may produce stress.
- Volatile-type silicone greases may permeate the product and produce cracks after long periods of time, resulting in reduced heat radiation effect, and possibly shortening the lifetime of the product.
- Our recommended silicone greases for heat radiation purposes, which will not cause any adverse effect on the product life, are indicated below:

Туре	Suppliers
G746	Shin-Etsu Chemical Co., Ltd.
YG6260	Momentive Performance Materials, Inc.
SC102	Dow Corning Toray Silicone Co., Ltd.

#### **Heatsink Mounting Method**

Torque When Tightening Mounting Screws. The recommended tightening torque for this product package type is: 58.8 to 78.4 N•cm (6.0 to 8.0 kgf•cm).

#### Soldering

• When soldering the products, please be sure to minimize the working time, within the following limits:

260±5°C 10 s

380±5°C 5 s

• Soldering iron should be at a distance of at least 1.5 mm from the body of the products

#### Electrostatic Discharge

- When handling the products, operator must be grounded. Grounded wrist straps worn should have at least 1 MΩ of resistance to ground to prevent shock hazard.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- When soldering the products, the head of soldering irons or the solder bath must be grounded in other to prevent leak voltages generated by them from being applied to the products.
- The products should always be stored and transported in our shipping containers or conductive containers, or be wrapped in aluminum foil.





The products described herein are manufactured in Japan by Sanken Electric Co., Ltd. for sale by Allegro MicroSystems, Inc.

Sanken and Allegro reserve the right to make, from time to time, such departures from the detail specifications as may be required to permit improvements in the performance, reliability, or manufacturability of its products. Therefore, the user is cautioned to verify that the information in this publication is current before placing any order.

When using the products described herein, the applicability and suitability of such products for the intended purpose shall be reviewed at the users responsibility.

Although Sanken undertakes to enhance the quality and reliability of its products, the occurrence of failure and defect of semiconductor products at a certain rate is inevitable.

Users of Sanken products are requested to take, at their own risk, preventative measures including safety design of the equipment or systems against any possible injury, death, fires or damages to society due to device failure or malfunction.

Sanken products listed in this publication are designed and intended for use as components in general-purpose electronic equipment or apparatus (home appliances, office equipment, telecommunication equipment, measuring equipment, etc.). Their use in any application requiring radiation hardness assurance (e.g., aerospace equipment) is not supported.

When considering the use of Sanken products in applications where higher reliability is required (transportation equipment and its control systems or equipment, fire- or burglar-alarm systems, various safety devices, etc.), contact a company sales representative to discuss and obtain written confirmation of your specifications.

The use of Sanken products without the written consent of Sanken in applications where extremely high reliability is required (aerospace equipment, nuclear power-control stations, life-support systems, etc.) is strictly prohibited.

The information included herein is believed to be accurate and reliable. Application and operation examples described in this publication are given for reference only and Sanken and Allegro assume no responsibility for any infringement of industrial property rights, intellectual property rights, or any other rights of Sanken or Allegro or any third party that may result from its use.

Copyright © 2008 Allegro MicroSystems, Inc. This datasheet is based on Sanken datasheet SSJ-03538





# High Voltage 3-Phase Motor Driver

## **Worldwide Contacts**

### Asia-Pacific

### China

## Sanken Electric Hong Kong Co., Ltd.

Suite 1026, Ocean Centre Canton Road, Tsimshatsui Kowloon, Hong Kong Tel: 852-2735-5262, Fax: 852-2735-5494

## Sanken Electric (Shanghai) Co., Ltd.

Room 3202, Maxdo Centre Xingyi Road 8, Changning District Shanghai, China Tel: 86-21-5208-1177, Fax: 86-21-5208-1757

### Taiwan Sanken Electric Co., Ltd.

Room 1801, 18th Floor 88 Jung Shiau East Road, Sec. 2 Taipei 100, Taiwan R.O.C. Tel: 886-2-2356-8161, Fax: 886-2-2356-8261

### Japan

## Sanken Electric Co., Ltd. Overseas Sales Headquarters

Metropolitan Plaza Building 1-11-1 Nishi-Ikebukuro, Toshima-ku Tokyo 171-0021, Japan Tel: 81-3-3986-6164, Fax: 81-3-3986-8637

### Korea

### Sanken Electric Korea Co., Ltd.

Samsung Life Yeouido Building 16F 23-10, Yeouido-Dong, Yeongdeungpo-gu Seoul 150-734, Korea Tel: 82-2-714-3700, Fax: 82-2-3272-2145

### Singapore

### Sanken Electric Singapore Pte. Ltd.

150 Beach Road, #14-03 The Gateway West Singapore 189720 Tel: 65-6291-4755, Fax: 65-6297-1744

### Europe

#### Sanken Power Systems (UK) Limited Pencoed Technology Park Pencoed, Bridgend CF35 5HY, United Kingdom Tel: 44-1656-869-100, Fax: 44-1656-869-162

## North America

### **United States**

Allegro MicroSystems, Inc. 115 Northeast Cutoff Worcester, Massachusetts 01606, U.S.A. Tel: 1-508-853-5000, Fax: 1-508-853-7895

### Allegro MicroSystems, Inc.

14 Hughes Street, Suite B105 Irvine, California 92618, U.S.A. Tel: 1-949-460-2003, Fax: 1-949-460-7837



